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# TRANSISTORS, HIGH POWER, PNP

# **BASED ON TYPE BUX78**

# ESCC Detail Specification No. 5204/006

Issue 7	November 2024



Document Custodian: European Space Agency - see https://escies.org



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# **DOCUMENTATION CHANGE NOTICE**

(Refer to https://escies.org for ESCC DCR content)

DCR No.	CHANGE DESCRIPTION
1684	Specification updated to incorporate changes per DCR.



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## 1 <u>GENERAL</u>

#### 1.1 <u>SCOPE</u>

This specification details the ratings, physical and electrical characteristics and test and inspection data for the component type variants and/or the range of components specified below. It supplements the requirements of, and shall be read in conjunction with, the ESCC Generic Specification listed under Applicable Documents.

#### 1.2 <u>APPLICABLE DOCUMENTS</u>

The following documents form part of this specification and shall be read in conjunction with it:

- (a) ESCC Generic Specification No. 5000
- (b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices

#### 1.3 <u>TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS</u>

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Basic Specification No. 21300 shall apply.

#### 1.4 THE ESCC COMPONENT NUMBER AND COMPONENT TYPE VARIANTS

#### 1.4.1 <u>The ESCC Component Number</u>

The ESCC Component Number shall be constituted as follows:

Example: 520400606

- Detail Specification Reference: 5204006
- Component Type Variant Number: 06 (as required)

#### 1.4.2 <u>Component Type Variants</u>

The component type variants applicable to this specification are as follows:

Variant Number	Based on Type	Case	Lead/Terminal Material and Finish	Weight max g
06	BUX78	TO-257	H2	5
07	BUX78	TO-257	H4	5

The lead/terminal material and finish shall be in accordance with the requirements of ESCC Basic Specification No. 23500.



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#### 1.5 MAXIMUM RATINGS

The maximum ratings shall not be exceeded at any time during use or storage.

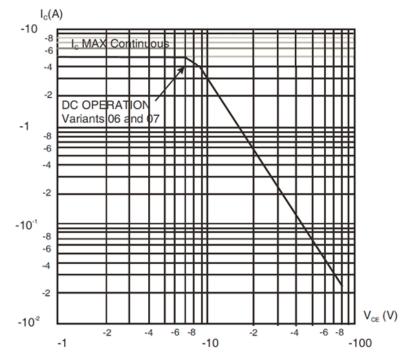
Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the ESCC Generic Specification.

Characteristics	Symbols	Maximum Ratings	Unit	Remarks
Collector-Base Voltage	Vсво	-100	V	Over T <sub>op</sub>
Collector-Emitter Voltage	Vceo	-80	V	Over T <sub>op</sub> Note 3
Emitter-Base Voltage	Vebo	-6	V	Over T <sub>op</sub>
Collector Current	lc	-5	A	Continuous, Note 3
Base Current	I <sub>B</sub>	-800	mA	Continuous
Power Dissipation	Ptot	35	W	At $T_{case} \le +25^{\circ}C$
Thermal Resistance, Junction-to-Case	Rth(j-c)	5	°C/W	-
Operating Temperature Range	T <sub>op</sub>	-65 to +200	°C	Note 1
Storage Temperature Range	T <sub>stg</sub>	-65 to +200	°C	Note 1
Soldering Temperature	T <sub>sol</sub>	+260	°C	Note 2

# NOTES:

- For Variant 07 with hot solder dip lead finish, all testing, and any handling, performed at T<sub>amb</sub> > +125 °C shall be carried out in a 100% inert atmosphere.
- 2. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.
- 3. Safe Operating Area applies as follows:

Maximum Safe Operating Area Graph





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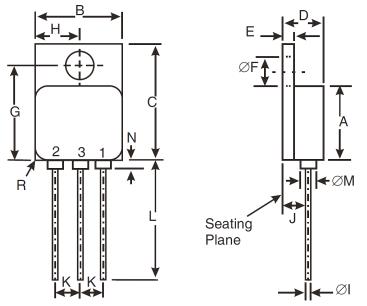
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## 1.6 HANDLING PRECAUTIONS

The TO-257 package (Variants 06, 07) contains Beryllium Oxide (BeO) and therefore it must not be ground, machined, sandblasted or subjected to any mechanical operation which will produce dust. The case must not be subjected to any chemical process (e.g. etching) which will produce fumes.

# 1.7 PHYSICAL DIMENSIONS AND TERMINAL IDENTIFICATION

1.7.1 Metal Flange Mount Package (TO-257) - 3 lead (Variants 06, 07)

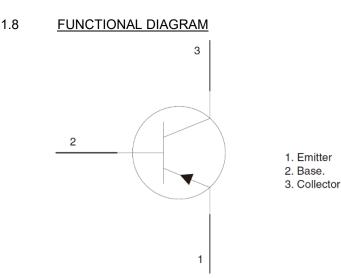


Symbols	Dimensi	Dimensions mm		
	Min	Max		
A	10.41	10.67		
В	10.41	10.67		
С	16.51	16.76		
D	4.7	5.33		
E	0.89	1.14		
ØF	3.56	3.81		
G	13.39	13.64		
Н	5.13	5.38		
ØI	0.64	0.89	2	
J	2.92	3.18		
К	2.41	2.67		
L	15.24	16.51		
ØM	2.29 Typical		2	
N	-	0.71	2	
R	1.65 T	ypical	3	

#### NOTES:

- 1. Terminal identification is specified by the component's geometry where Lead 1 = emitter, Lead 2 = base and Lead 3 = collector.
- 2. Applies to all leads.
- 3. Radius of body corner, 4 places.





# NOTES:

The case is not connected to any lead.

## 1.9 MATERIALS AND FINISHES

Materials and finishes shall be as follows:

- (a) Case The case shall be hermetically sealed and have a metal body. The leads pass through ceramic eyelets brazed into the frame and the lid shall be welded.
- (b) Leads/Terminals As specified in Para. 1.4.2 Component Type Variants.

# 2 <u>REQUIREMENTS</u>

2.1 <u>GENERAL</u>

The complete requirements for procurement of the components specified herein are as stated in this specification and the ESCC Generic Specification. Permitted deviations from the Generic Specification, applicable to this specification only, are listed below.

Permitted deviations from the Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirement and do not affect the component's reliability, are listed in the appendices attached to this specification.

2.1.1 <u>Deviations from the Generic Specification</u> None.



# 2.2 <u>MARKING</u>

The marking shall be in accordance with the requirements of ESCC Basic Specification No. 21700 and as follows.

The information to be marked on the component shall be:

- (a) The ESCC qualified components symbol (for ESCC qualified components only).
- (b) The ESCC Component Number (see Para. 1.4.1).
- (c) Traceability information.
- (d) Warning sign for Beryllium Oxide.

#### 2.3 <u>TERMINAL STRENGTH</u>

The test conditions for terminal strength, tested as specified in the ESCC Generic Specification, shall be as follows:

• Test Condition A, tension, with an applied force of 10N for a duration of 10s.

## 2.4 VERIFICATION OF SAFE OPERATING AREA

The Safe Operating Area shall be verified as specified in the ESCC Generic Specification and Para. 1.5 Maximum Ratings herein. The test conditions shall be:

- Test Method = MIL-STD-750, Method 3051, Continuous DC
- T<sub>case</sub> = +25 °C
- V<sub>CE</sub> = -12V
- Ic = -2A
- Operating Time ≤ 100ms

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#### 2.5 <u>ELECTRICAL MEASUREMENTS AT ROOM, HIGH AND LOW TEMPERATURES</u> Electrical measurements shall be performed at room, high and low temperatures.

# 2.5.1 <u>Room Temperature Electrical Measurements</u>

The measurements shall be performed at  $T_{amb}$  = +22 ±3°C.

Characteristics	Symbols	MIL-STD-750	Test Conditions	Lim	its	Units
		Test Method		Min	Max	
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	3011	I <sub>C</sub> = -50mA, Bias condition D Note 1	-80	-	V
	V <sub>(BR)CES</sub>	3011	I <sub>C</sub> = -2mA, Bias condition C	-100	-	V
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	3026	$I_E$ = -1mA, Bias condition D	-6	-	V
Collector-Emitter Cut-off Current	I <sub>CEO</sub>	3041	$V_{CE}$ = -60V, Bias condition D	-	-10	μA
Collector-Base Cut-off Current	Ісво	3036	$V_{CB}$ = -80V, Bias condition D	-	-500	nA
Emitter-Base Cut-off Current	I <sub>EBO</sub>	3061	V <sub>EB</sub> = -4V, Bias condition D	-	-500	nA
Forward-Current Transfer Ratio	h <sub>FE1</sub>	3076	V <sub>CE</sub> = -5V, I <sub>C</sub> = -500mA Note 1	70	-	-
	h <sub>FE2</sub>		V <sub>CE</sub> = -5V, I <sub>C</sub> = -2A Note 1	50	200	-
	h <sub>FE3</sub>		V <sub>CE</sub> = -5V, I <sub>C</sub> = -5A Note 1	30	-	-
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	3071	I <sub>C</sub> = -5A, I <sub>B</sub> = -500mA Notes 1, 2	-	-1	V
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	3066	$I_{C}$ = -5A, $I_{B}$ = -500mA Test condition A Notes 1, 2	-	-1.3	V
High Frequency Small Signal Current Gain	h <sub>fe</sub>	3306	$V_{CE}$ = -5V, I <sub>C</sub> = -500mA f = 20MHz Note 3	2.5	-	-
Turn-on Time	ton	-	I <sub>C</sub> = -5A, I <sub>B1</sub> = -500mA I <sub>B2</sub> = 500mA, V <sub>CC</sub> = -40V V <sub>BB</sub> = 4V, V <sub>IN</sub> ≈ -51V Notes 3, 4	-	300	ns
Turn-off Time	t <sub>off</sub>	-	$\label{eq:lc} \begin{array}{l} I_{C} = -5A, \ I_{B1} = -500 mA \\ I_{B2} = 500 mA, \ V_{CC} = -40V \\ V_{BB} = 4V, \ V_{IN} \approx -51V \\ Notes \ 3, \ 4 \end{array}$	-	700	ns

# NOTES:

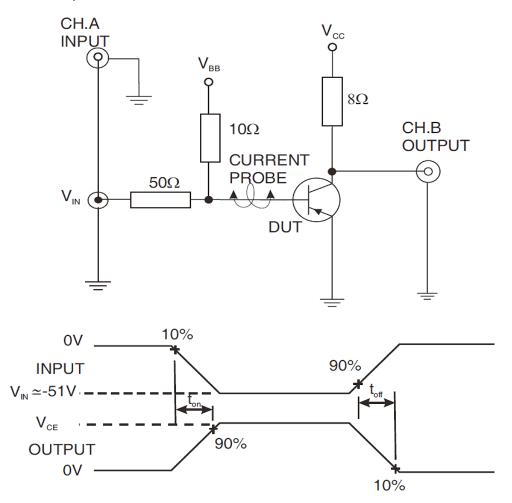
- 1. Pulsed measurement: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 2. Saturation voltages are measured 6mm from the case.
- 3. For AC characteristics, read and record measurements shall be performed on a sample of 32 components with 0 failures allowed. Alternatively, a 100% inspection may be performed.

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4. ton and toff shall be measured using the following test circuit. The input waveform shall be supplied by a pulse generator with the following characteristics:  $t_r \le 20$ ns, Pulse Width = 10µs, Duty Cycle = 1%. The sampling oscilloscope for CH.A and CH.B shall have the characteristics  $Z_{IN} \ge 100$ k $\Omega$ ,  $C_{IN} \le 12$ pF and  $t_r \le 5$ ns. Adjustment of V<sub>IN</sub> shall be made with a suitable current probe to achieve the specified I<sub>B1</sub> and I<sub>B2</sub> test conditions, where I<sub>B1</sub> is the on-state base current and I<sub>B2</sub> is the post off-state base current.





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## 2.5.2 <u>High and Low Temperatures Electrical Measurements</u>

Characteristics	Symbols	MIL-STD-750	Test Conditions	Lin	nits	Units
		Test Method	Note 1	Min	Max	
Collector-Base Cut-off Current	Ісво	3036	$T_{amb}$ = +150 (+0 -5)°C V <sub>CE</sub> = -80V, Bias Condition D	-	-150	μA
Forward-Current Transfer Ratio 4	hfe4	3076	$T_{amb}$ = -55 (+5 -0)°C V <sub>CE</sub> = -5V, I <sub>C</sub> = -1A Note 2	25	-	-

## NOTES:

- 1. Read and record measurements shall be performed on a sample of 5 components with 0 failures allowed. Alternatively, a 100% inspection may be performed.
- 2. Pulsed measurement: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

#### 2.6 PARAMETER DRIFT VALUES

Unless otherwise specified, the measurements shall be performed at  $T_{amb}$  = +22 ±3°C.

The test methods and test conditions shall be as per the corresponding test defined in Para. 2.5.1 Room Temperature Electrical Measurements.

The drift values ( $\Delta$ ) shall not be exceeded for each characteristic specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits			Units
		Drift	Absolute		
		Value Δ	Min	Max	
Emitter-Base Cut-off Current	I <sub>EBO</sub>	±100	-	-500	nA
Forward-Current Transfer Ratio 2	h <sub>FE2</sub>	±25%	50	200	-
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	±100	-	-1000	mV

#### 2.7 INTERMEDIATE AND END-POINT ELECTRICAL MEASUREMENTS

Unless otherwise specified, the measurements shall be performed at  $T_{amb}$  = +22 ±3°C.

The test methods and test conditions shall be as per the corresponding test defined in Para. 2.5.1 Room Temperature Electrical Measurements.

The limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits		Units
		Min	Max	
Collector-Emitter Cut-off Current	ICEO	-	-10	μA
Forward-Current Transfer Ratio 2	h <sub>FE2</sub>	50	200	-
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	-	-1	V



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# 2.8 <u>HIGH TEMPERATURE REVERSE BIAS BURN-IN CONDITIONS</u>

Characteristics	Symbols	Conditions	Units
Ambient Temperature	$T_{amb}$	+150 (+0 -5)	°C
Emitter-Base Voltage	$V_{EB}$	-4.5	V
Collector-Base Voltage	V <sub>CB</sub>	-80	V
Duration	t	48 minimum	hours

## NOTES:

1. No heat sink nor forced air directly on the device shall be permitted.

# 2.9 POWER BURN-IN CONDITIONS

Characteristics	Symbols	Conditions	Units
Case Temperature	T <sub>case</sub>	+100 (+0 -5)	°C
Power Dissipation	P <sub>tot</sub>	As per Para. 1.5 Maximum Ratings. Derate P <sub>tot</sub> at the specified T <sub>case</sub> using the specified R <sub>th(j-c)</sub> .	W
Collector-Base Voltage	V <sub>CB</sub>	-10	V

# 2.10 OPERATING LIFE CONDITIONS

The conditions shall be as specified in Para. 2.9, Power Burn-in Conditions.

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# <u>APPENDIX A</u>

# AGREED DEVIATIONS FOR STMICROELECTRONICS (F)

ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS
Para. 2.1.1, Deviations from the Generic Specification: Para. 8, Test Methods and Procedures	For qualification and qualification maintenance, or procurement of qualified or unqualified components, the following replacement test method specifications shall be used instead of the following ESCC Basic Specifications:
	No. 20400, Internal Visual Inspection: replaced by MIL-STD-750 Test Method 2072.
	No. 20500, External Visual Inspection: replaced by MIL-STD-750 Test Method 2071.
	No. 20900, Radiographic Inspection of Electronic Components: replaced by MIL-STD-750 Test Method 2076
Para. 2.1.1, Deviations from the Generic Specification: Deviations from Screening Tests - Chart F3	Solderability is not applicable unless specifically stipulated in the Purchase Order.
Para. 2.5.1, Room Temperature Electrical Measurements	All AC characteristics (i.e. Para. 2.5.1 Note 2) may be considered guaranteed but not tested if successful pilot lot testing has been performed on the wafer lot which includes AC characteristic measurements per the Detail Specification.
	A summary of the pilot lot testing shall be provided if required by the Purchase Order.
Para. 2.5.2, High and Low Temperatures Electrical Measurements	All characteristics specified may be considered guaranteed but not tested if successful pilot lot testing has been performed on the wafer lot which includes characteristic measurements at high and low temperatures per the Detail Specification.
	A summary of the pilot lot testing shall be provided if required by the Purchase Order.